# Micro-Opto-Mechanical Systems

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Microelectromechanical Systems (MEMS)

## Opto-Mechanical Devices using MEMS Technology

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#### Outline

- motivation
- devices
- systems

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#### Motivation

with low unit cost assembled optical system that can be mass produced microelectronics in order to realize a complete prepassive/active optical components, microsensors, and coordinated motions of basic microactuators, The ultimate goal of MOMS is to integrate

of microfabricated opto-mechanical systems which: MOMS will allow the development of new families

- do not need component alignment;
- can be mass produced (i.e., are on the order of dollars per unit device);
- have high packing density;
- can be directly integrated with electronics; and
- are low-power, small, and light weight.

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## We are at the device stage

- microscanners
- tunable laser diodes
- optical waveguides
- microrelays

## Where are are going?

telecommunications industry integrated systems especially for the

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## Put individual devices into microoptical-mechanical systems

- scanners, beam steering microscanners  $\rightarrow$  optical switches,
- systems tunable laser diodes -> communications
- $microrelays \rightarrow instrumentation$

## Integrate individual devices to create micro-optical-mechanical systems

- optical waveguides are an enabling technology
- optical duplexer for subscriber loop services

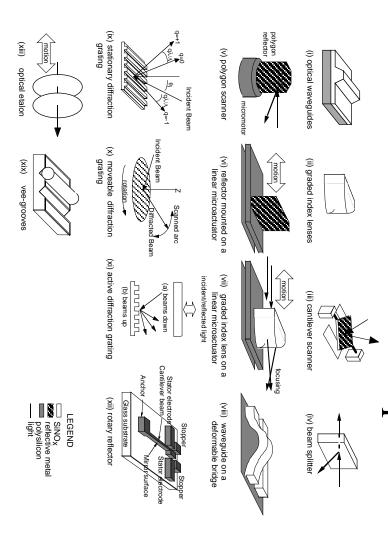
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MOMS critical to practical implementation of large numbers of fiber optic subscriber loops

- optical microbenches that permit low-cost manufacture of pre-aligned, microbench as one of the industry's most pressing short-term needs Reliance Electric Comm-Tech has identified such an optical assembly hybrid fiber optic systems (e.g., transmitters and receivers)
- optical switches which permit in-situ testing of optical fibers
- low-cost, mass-produced <u>frequency stabilized laser diode sources</u> for WDM and other applications

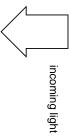
# Set of basic MOM components

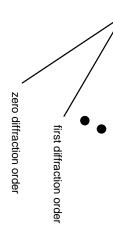


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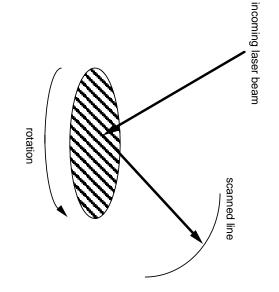
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## Diffraction grating





### Schematic diagram of a rotating diffraction grating scanner.

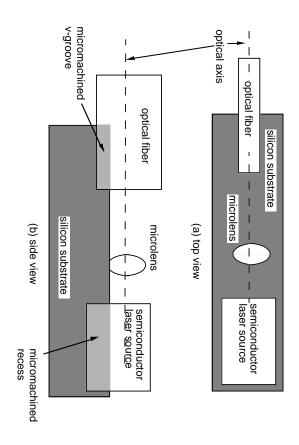


Note that the incident beam reflects from the entire rotor surface

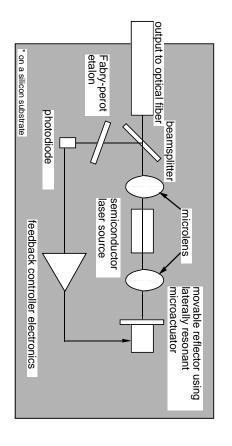
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microbench based on a silicon chip. Schematic illustration of an optical



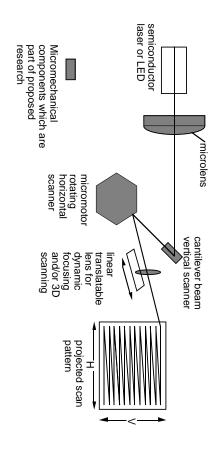
#### Conceptual external cavity frequency stabilized laser diode using a lateral resonant mirror translator



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### microfabricated 3D scanner for miniature projection displays



The micromotor scanner will also be used for optical switches.

Our industrial partner, Reliance Electric

- proceeds carrying out their research and will be directly involved as the program on-site interactions will result in a natural technology transfer path. In proposed and helped us in defining specific needs and applications. Our Reliance Electric is genuinely interested in the technology being fact, their technical contacts will co-supervise the graduate students
- The results of our basic research on enabling technologies, (generic) appropriate patent protection is obtained by CWRU or Reliance applications with promising markets will be considered proprietary until proprietary. However, in the course of the research, devices and device designs, and prototype performance characteristics are not available to ARPA for government use. Electric. The results of all portions of the program will be made

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## the fiber optic coupler

- as the short term application of the optical microbench a vee-groove multiple optical fiber coupler was identified technology
- Specifications for a commercial device were provided by Reliance Electric after several joint meetings
- a prototype device was designed and fabricated at CWRU
- this device was sent to Reliance telecommunications in Chicago for testing
- device passed AT&T coupler specifications

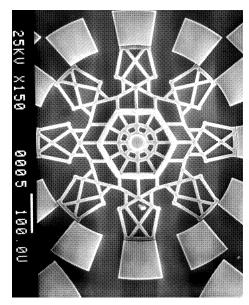
### **Continuing Collaboration with Reliance** the project team

- Research Dr. Jim Harris, Fred Discenzo, Reliance
- Dr. George Ab-Bubu, Reliance Telecommunications
- Prof. Frank Merat, Prof. Mehran Mehregany, CWRU
- Shuvo Roy, Steve Smith, Azzam Yaseen, CWRU Ph.D. candidates

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## Polygon Microscanner



approximately 175 microns in diameter electroless-plating of nickel reflecting surfaces on the rotor of a 500 nickel is 20  $\mu m$ ; the width of the nickel is 10  $\mu m$ . The polygon itself is micron diameter salient-pole micromotor. The thickness (height) of the SEM photo of a rotating polygon optical microscanner made by

## Scanner optical beam

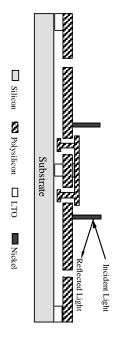


from the scanner using an ordinary TV camera. polygon scanner. The image was recorded approximately 10 inches Digitized video image of a 633-nm laser beam reflecting from the

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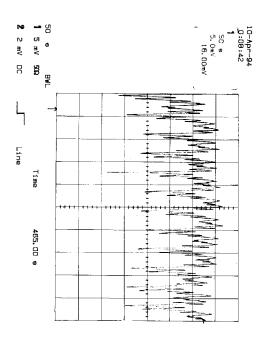
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## Cross-sectional schematic of a typical polygon microscanner



surface with a laser beam. Note that if the reflector is too far from the Typical microscanner after release showing illumination of the nickel rotor rim the beam will also reflect from the rotor surface

## Reflected signals from a spinning rotor with a constant rotor speed

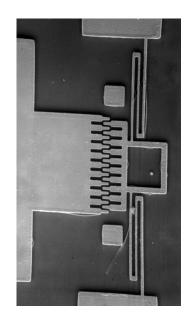


wobble of the rotor about the axis of rotation. The low frequency variation of the reflectivity is hypothesized to be a low frequency The complex shape of the reflection is caused by undesired reflections from the rotor.

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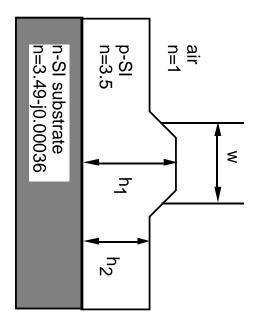
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### Electrostatic drive lateral translational reflector.



and will be used as an optical reflector. The sidewall of the surface at the top center of the image is nickel plated

## Cross-sectional view of a rib waveguide in epitaxial silicon



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### Schematic diagram of optical duplexer chip

Photodetector to

Optical fiber to substation

Photodetector to monitor laser diode

High-speed
Photodetector for video information

Laser diode source

# Single Mode Pigtailed 1.3/1.3 Duplexer

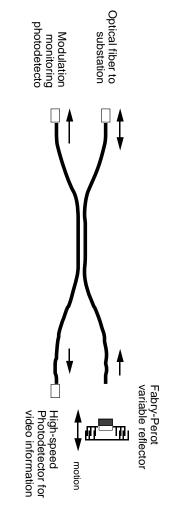
Item	Symbol	Conditions	À IZ	MAX	Units
Operating case temp	Tc	1	40	85	8
Wavelength	lc	over Tc	1260	1350	nm
Output power into	Pout	over Tc	6	(see Pfth)	μW
single mode fiber					
Threshold power (Laser diode) Pfth	Pfth	over Tc		min Pout/30 μW	μW
Crosstalk (Note 1)	$C_r$	over Tc		-29	dВ
Tracking error (Note 2)	Er.	over Tc	3, 0.5		dB
Receiver responsivity	R	over Tc	0.3		A/W
Receiver polarization	Rp	over Tc		1	dB
dependence					
Receiver capacitance	ССС	-5 V bias		1	pF
Receiver dark current	Id	over Tc, -5 V	<	10	nA
SC-PC connector loss	IL	over Tc		0.5	dB
Connector reflectance	Rc	over Tc		-33	dB
Backward reflectance	Rb	over Tc		-20	dB

If total tracking error Er<0.5 dB, then crosstalk Cr<-24 dB</li>
 If total tracking error 0.5
 dB, then crosstalk Cr<-29 dB</li>

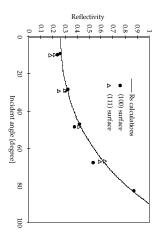
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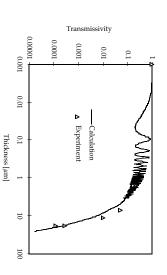
#### micromechanical light modulator to Optical duplexer using planar replace optical source.



## Optical properties of high-aspect-ratio (111) silicon plates



Reflectivity as a function of the light beam incident angle

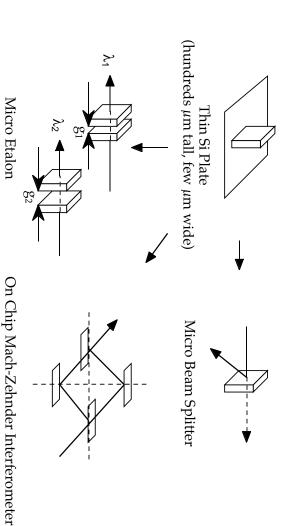


Transmissivity as a function of the thickness of the (111) silicon plate

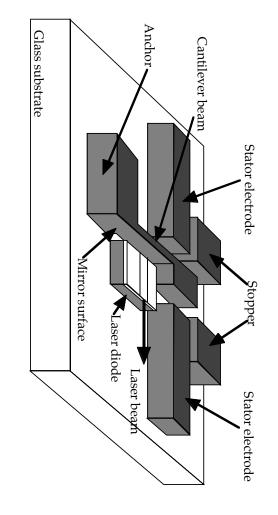
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## Optical applications of high-aspect-ratio (111) silicon plates



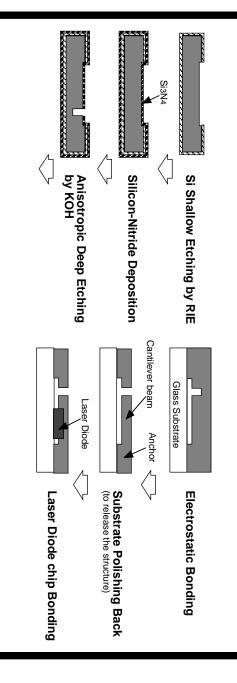
## Schematic diagram of an integrated laser diode and micromirror



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## integrated laser diode/micromirror Fabrication process for the



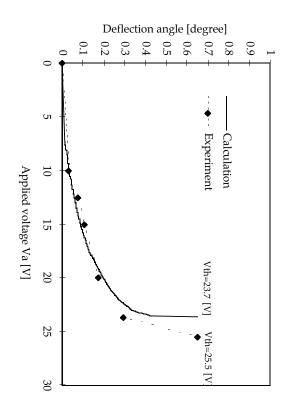
## An SEM image of the integrated laser diode and micromirror.



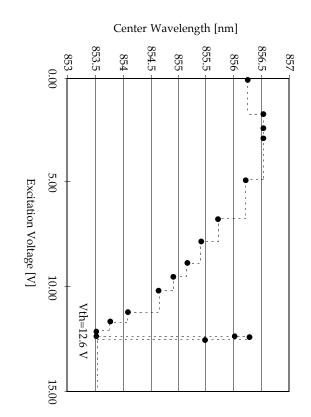
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## Micromirror deflection angle as a function of the applied voltage



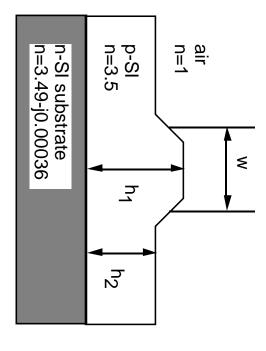
## Wavelength variation as a function of the excitation voltage of the mirror



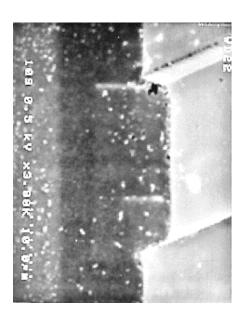
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### waveguide in epitaxial silicon Cross-sectional view of a rib



## Anisotropically-etched waveguide end-face

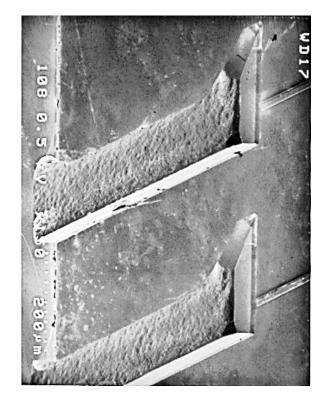


is the heavily doped silicon substrate The dark layer is the region where light is guided and the light layer

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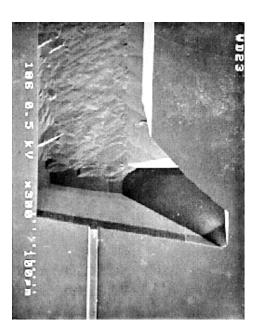
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# End view of bulk fabricated U-grooves



Note the rib waveguides positioned at the end of the grooves and the corner compensation structures

Detail of corner compensation structure of fiber guiding U-groove on a (110) silicon substrate

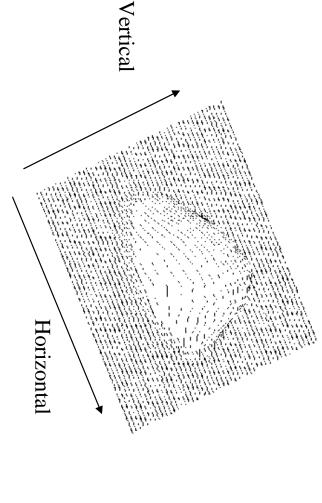


Note the rib waveguide at the right end of the U-groove

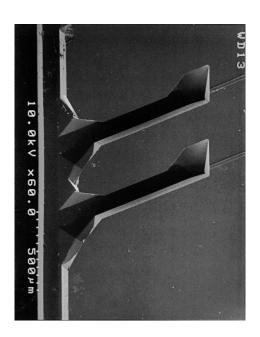
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area, all-silicon waveguide with a 10 µm wide rib Three dimensional intensity profile from a large-



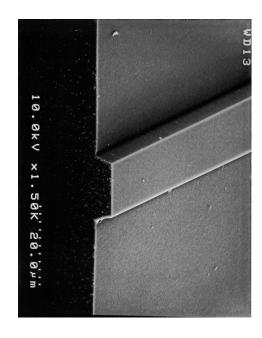
## End view of bulk fabricated U-grooves using ultrasonic agitation



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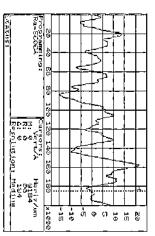
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## Anistropically etched rib waveguide with ultrasonic agitation

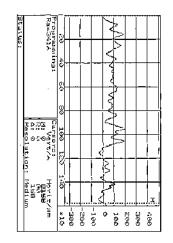


# U-groove surface roughness

Decktak surface roughness of a typical U-groove bottom. The value of Ra is 5606Å.



Decktak surface roughness of a U-groove bottom produced with ultrasonic etching. The value of Ra is 341Å



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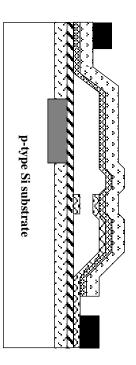
### Microrelays:

## **Background and Motivation**

- Surface micromachining concept
- "Traditional" high-aspect-ratio microstructures

- **New Surface Micromachining Process**
- Mold characteristics
- Structural material deposition

## Polysilicon Surface–Micromachined Relay (Gretillat et. al at MEMS '94)



- final doped polysilicon
- aluminum
- silicon nitride

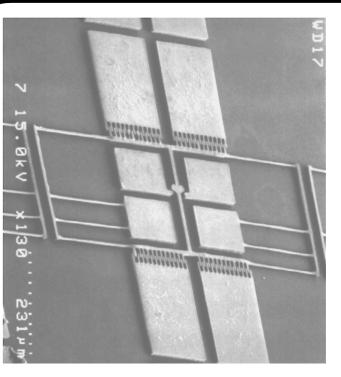
oxide and silicon nitride

- initial doped polysilicon
- p-type region n-type region
- Low current load  $\approx 1 \text{ mA}$
- High contact resistance  $\approx 10 \text{ k}\Omega$

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## Nickel Microrelays



- \* Metallic contacts
- electrostatic actuation
- rubbing action
- stiff suspension



## Microrelay Characterization

Actuation voltages

 $\approx 200 \text{ Volts}$ 

- Resonant frequencies 5–20 kHz
- Current load

 $\approx 250 \text{ mA}$ 

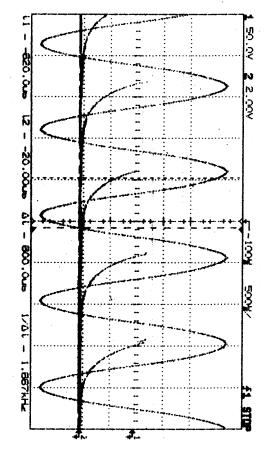
Contact resistance

 $< 20 \Omega$ 

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# icrorelay Switching Operation



- frequency ≈ 1 kHz
- switched signal  $\approx 5$  Volts
- contact travel ≈ 2 µm
- contact force  $\approx 20 \,\mu\text{N}$